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Kind regards,

Team Nexperia



PBSS301PX

12 V, 5.3 A PNP low V_{CEsat} (BISS) transistor

Rev. 02 — 17 November 2009

Product data sheet

1. Product profile

1.1 General description

PNP low V_{CEsat} Breakthrough In Small Signal (BISS) transistor in a SOT89 (SC-62/TO-243) small and flat lead Surface-Mounted Device (SMD) plastic package.

NPN complement: PBSS301NX.

1.2 Features

- Low collector-emitter saturation voltage V_{CEsat}
- High collector current capability I_C and I_{CM}
- High collector current gain (h_{FE}) at high I_C
- High efficiency due to less heat generation
- Smaller required Printed-Circuit Board (PCB) area than for conventional transistors

1.3 Applications

- DC-to-DC conversion
- MOSFET gate driving
- Motor control
- Charging circuits
- Power switches (e.g. motors, fans)

1.4 Quick reference data

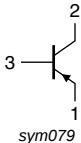
Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{CEO}	collector-emitter voltage	open base	-	-	-12	V
I_C	collector current		-	-	-5.3	A
I_{CM}	peak collector current	single pulse; $t_p \leq 1$ ms	-	-	-10.6	A
R_{CEsat}	collector-emitter saturation resistance	$I_C = -4$ A; $I_B = -200$ mA	^[1] -	28	40	m Ω

[1] Pulse test: $t_p \leq 300$ μ s; $\delta \leq 0.02$.

2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Symbol
1	emitter		 sym079
2	collector		
3	base		

3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PBSS301PX	SC-62	plastic surface-mounted package; collector pad for good heat transfer; 3 leads	SOT89

4. Marking

Table 4. Marking codes

Type number	Marking code ^[1]
PBSS301PX	*5H

- [1] * = -: made in Hong Kong
 * = p: made in Hong Kong
 * = t: made in Malaysia
 * = W: made in China

5. Limiting values

Table 5. Limiting values
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CBO}	collector-base voltage	open emitter	-	−12	V
V _{CEO}	collector-emitter voltage	open base	-	−12	V
V _{EBO}	emitter-base voltage	open collector	-	−5	V
I _C	collector current		-	−5.3	A
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms	-	−10.6	A
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1] -	0.6	W
			[2] -	1.65	W
			[3] -	2.1	W
T _j	junction temperature		-	150	°C
T _{amb}	ambient temperature		−65	+150	°C
T _{stg}	storage temperature		−65	+150	°C

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².
[3] Device mounted on a ceramic PCB, Al₂O₃, standard footprint.

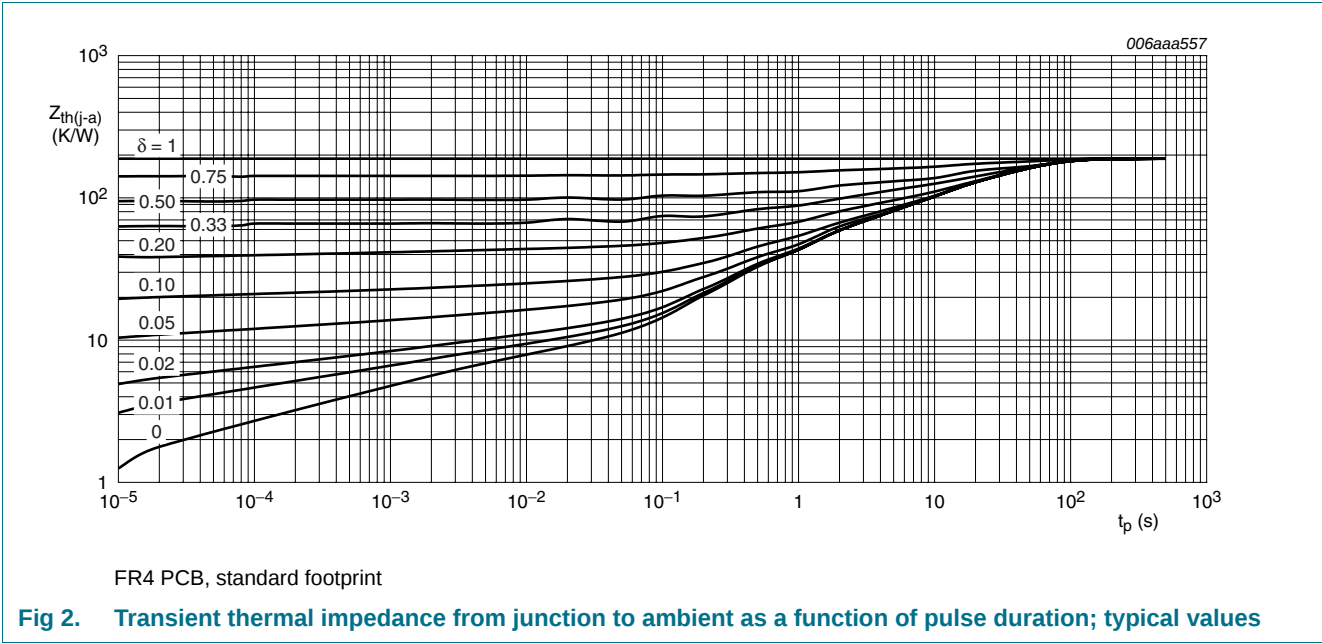


6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1] -	-	208	K/W
			[2] -	-	76	K/W
			[3] -	-	60	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point		-	-	20	K/W

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².
[3] Device mounted on a ceramic PCB, Al₂O₃, standard footprint.





FR4 PCB, mounting pad for collector 6 cm²

Fig 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



Ceramic PCB, Al₂O₃, standard footprint

Fig 4. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

7. Characteristics

Table 7. Characteristics

$T_{amb} = 25\text{ }^{\circ}\text{C}$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
I_{CBO}	collector-base cut-off current	$V_{CB} = -12\text{ V}; I_E = 0\text{ A}$	-	-	-100	nA
		$V_{CB} = -12\text{ V}; I_E = 0\text{ A}; T_j = 150\text{ }^{\circ}\text{C}$	-	-	-50	μA
I_{EBO}	emitter-base cut-off current	$V_{EB} = -5\text{ V}; I_C = 0\text{ A}$	-	-	-100	nA
h_{FE}	DC current gain	$V_{CE} = -2\text{ V}; I_C = -0.5\text{ A}$	[1] 250	400	-	
		$V_{CE} = -2\text{ V}; I_C = -1\text{ A}$	[1] 250	380	-	
		$V_{CE} = -2\text{ V}; I_C = -2\text{ A}$	[1] 200	335	-	
		$V_{CE} = -2\text{ V}; I_C = -4\text{ A}$	[1] 150	250	-	
		$V_{CE} = -2\text{ V}; I_C = -6\text{ A}$	[1] 130	200	-	
V_{CEsat}	collector-emitter saturation voltage	$I_C = -0.5\text{ A}; I_B = -50\text{ mA}$	[1] -	-20	-30	mV
		$I_C = -1\text{ A}; I_B = -50\text{ mA}$	[1] -	-40	-60	mV
		$I_C = -1\text{ A}; I_B = -10\text{ mA}$	[1] -	-60	-90	mV
		$I_C = -2\text{ A}; I_B = -40\text{ mA}$	[1] -	-70	-100	mV
		$I_C = -4\text{ A}; I_B = -200\text{ mA}$	[1] -	-115	-160	mV
		$I_C = -4\text{ A}; I_B = -400\text{ mA}$	[1] -	-110	-155	mV
		$I_C = -4\text{ A}; I_B = -40\text{ mA}$	[1] -	-150	-240	mV
		$I_C = -5.3\text{ A}; I_B = -265\text{ mA}$	[1] -	-145	-210	mV
R_{CEsat}	collector-emitter saturation resistance	$I_C = -4\text{ A}; I_B = -200\text{ mA}$	[1] -	28	40	$\text{m}\Omega$
		$I_C = -4\text{ A}; I_B = -40\text{ mA}$	[1] -	38	60	$\text{m}\Omega$
V_{BEsat}	base-emitter saturation voltage	$I_C = -1\text{ A}; I_B = -100\text{ mA}$	[1] -	-0.82	-0.9	V
		$I_C = -4\text{ A}; I_B = -400\text{ mA}$	[1] -	-0.93	-1.05	V
V_{BEon}	base-emitter turn-on voltage	$V_{CE} = -2\text{ V}; I_C = -2\text{ A}$	[1] -	-0.76	-0.85	V
t_d	delay time	$V_{CC} = -12.5\text{ V}; I_C = -3\text{ A}; I_{Bon} = -0.15\text{ A}; I_{Boff} = 0.15\text{ A}$	-	10	-	ns
t_r	rise time		-	55	-	ns
t_{on}	turn-on time		-	65	-	ns
t_s	storage time		-	165	-	ns
t_f	fall time		-	160	-	ns
t_{off}	turn-off time		-	325	-	ns
f_T	transition frequency	$V_{CE} = -10\text{ V}; I_C = -0.1\text{ A}; f = 100\text{ MHz}$	-	140	-	MHz
C_c	collector capacitance	$V_{CB} = -10\text{ V}; I_E = I_C = 0\text{ A}; f = 1\text{ MHz}$	-	190	250	pF

[1] Pulse test: $t_p \leq 300\text{ }\mu\text{s}$; $\delta \leq 0.02$.

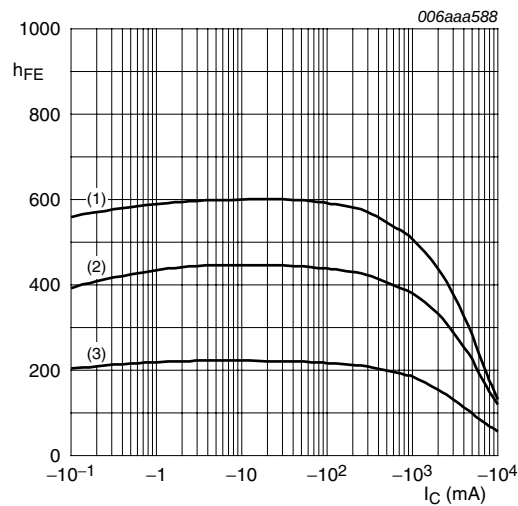


Fig 5. DC current gain as a function of collector current; typical values

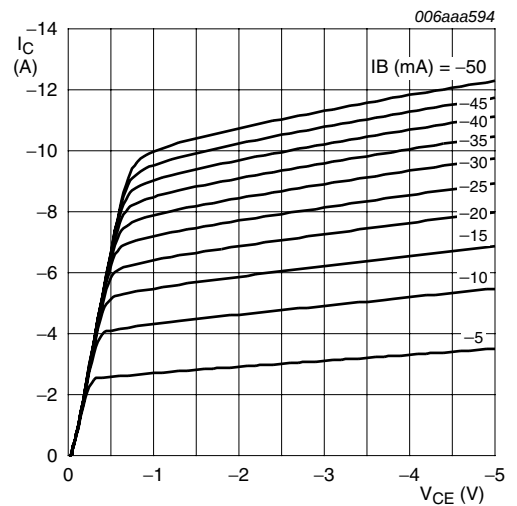


Fig 6. Collector current as a function of collector-emitter voltage; typical values

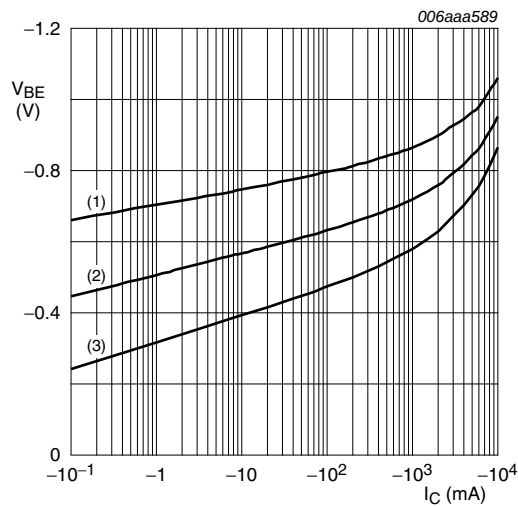


Fig 7. Base-emitter voltage as a function of collector current; typical values

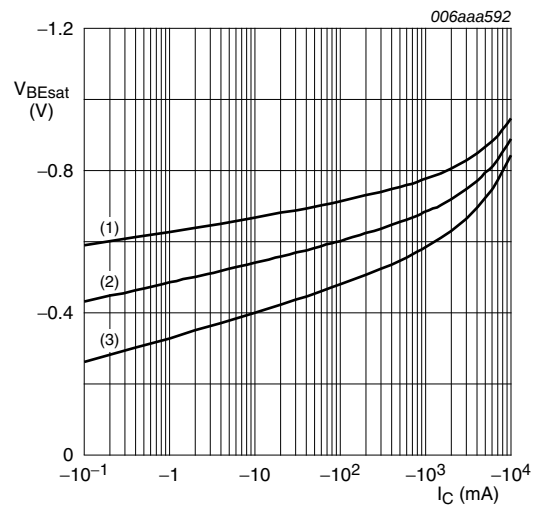


Fig 8. Base-emitter saturation voltage as a function of collector current; typical values

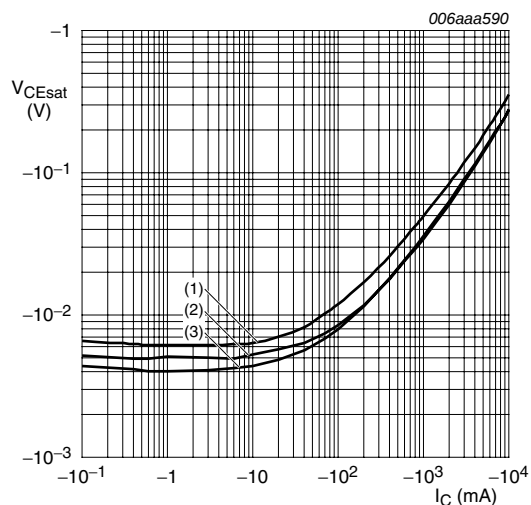


Fig 9. Collector-emitter saturation voltage as a function of collector current; typical values

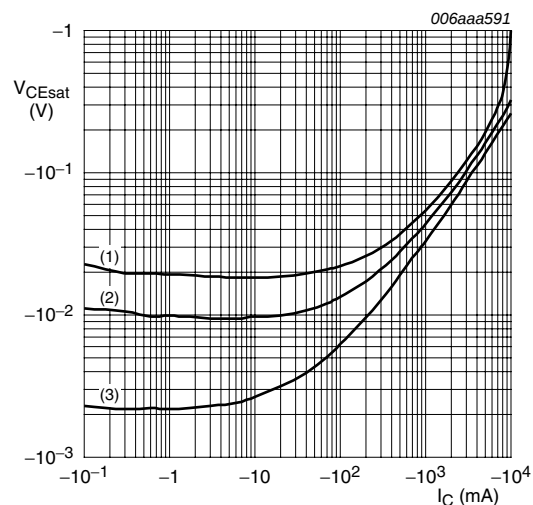


Fig 10. Collector-emitter saturation voltage as a function of collector current; typical values

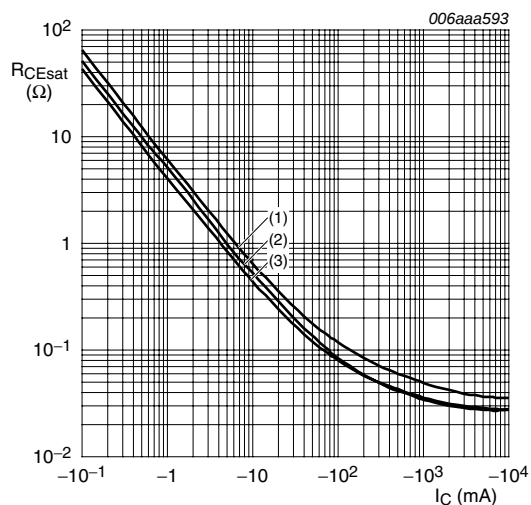


Fig 11. Collector-emitter saturation resistance as a function of collector current; typical values

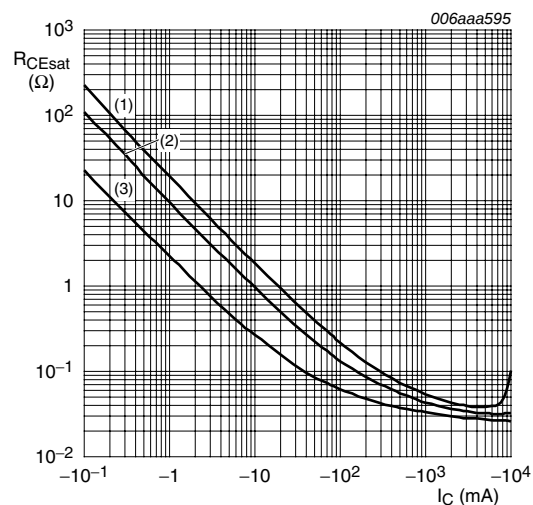


Fig 12. Collector-emitter saturation resistance as a function of collector current; typical values

8. Test information

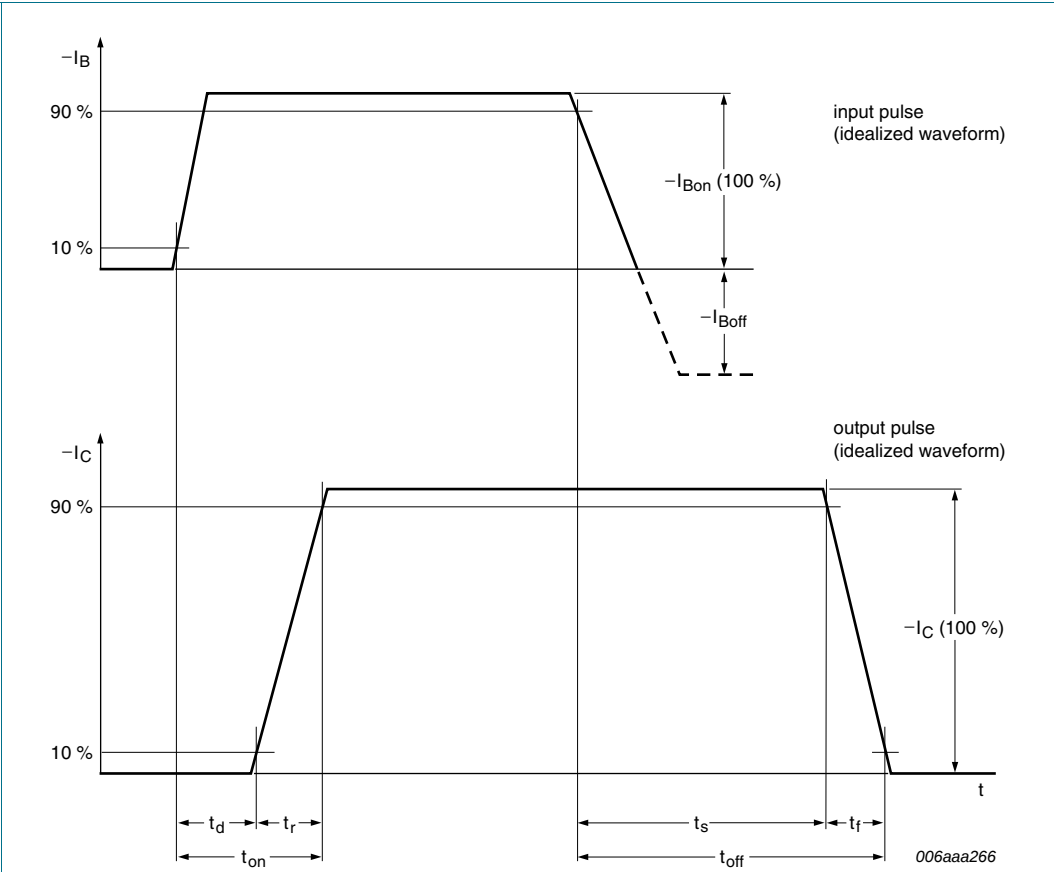


Fig 13. BISS transistor switching time definition

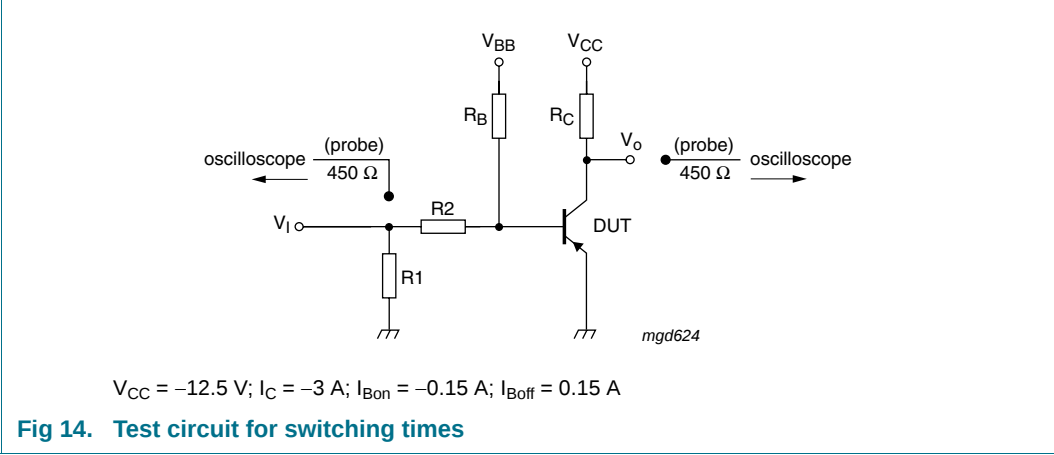


Fig 14. Test circuit for switching times

9. Package outline



10. Packing information

Table 8. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.^[1]

Type number	Package	Description	Packing quantity	
			1000	4000
PBSS301PX	SOT89	8 mm pitch, 12 mm tape and reel	-115	-135

[1] For further information and the availability of packing methods, see [Section 15](#).

11. Soldering

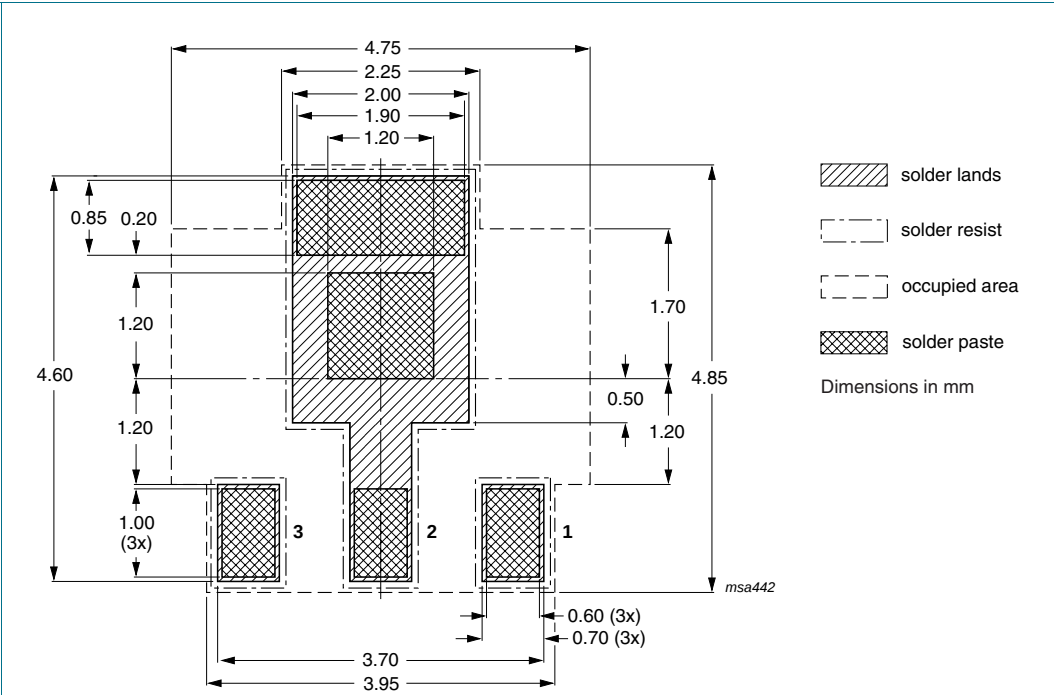
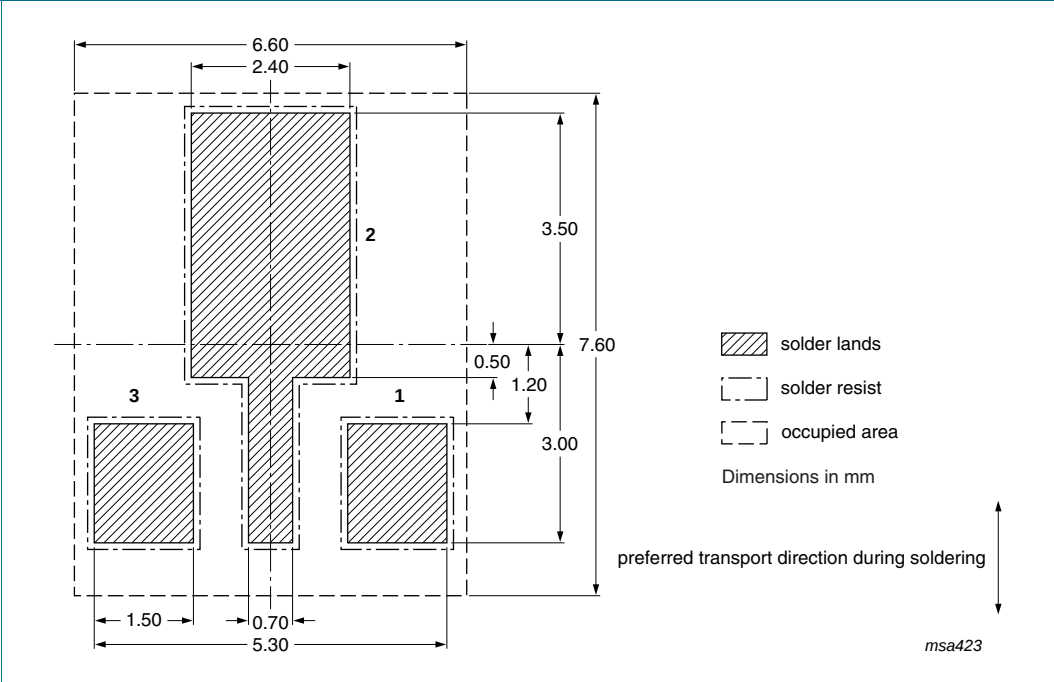
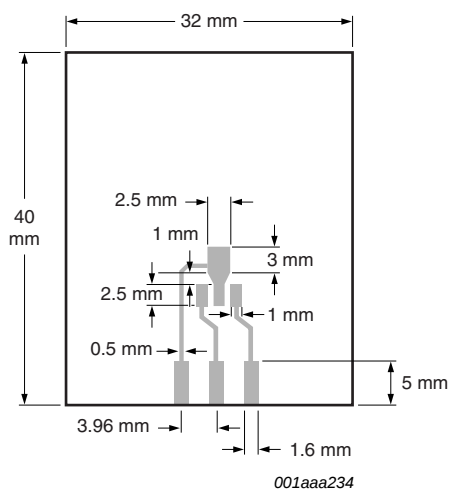


Fig 16. Reflow soldering footprint SOT89 (SC-62)



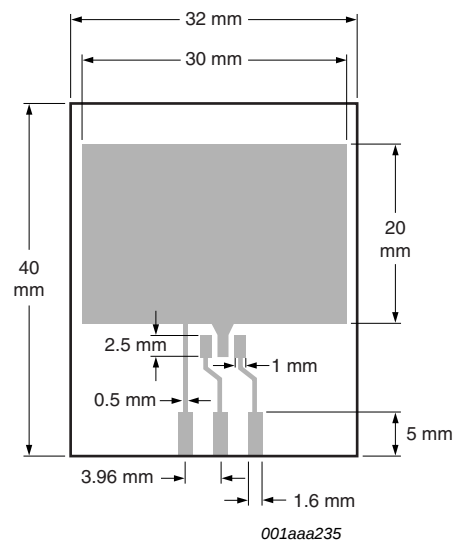
Not recommended for wave soldering
Fig 17. Wave soldering footprint SOT89 (SC-62)

12. Mounting



PCB thickness:
FR4 PCB = 1.6 mm
ceramic PCB = 0.635 mm

Fig 18. FR4 PCB, standard footprint;
ceramic PCB, Al_2O_3 , standard
footprint SOT89 (SC-62)



PCB thickness = 1.6 mm

Fig 19. FR4 PCB, mounting pad for
collector 6 cm² SOT89 (SC-62)

13. Revision history

Table 9. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PBSS301PX_2	20091117	Product data sheet	-	PBSS301PX_1
Modifications:	• This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content. • Figure 15 "Package outline SOT89 (SC-62/TO-243)": updated • Figure 16 "Reflow soldering footprint SOT89 (SC-62)": updated • Figure 17 "Wave soldering footprint SOT89 (SC-62)": updated			
PBSS301PX_1	20060821	Product data sheet	-	-

14. Legal information

14.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.



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